







	<p>Hersteller-Teilenummer: SI1307EDL-T1-GE3</p>
	<p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p>
	<p>Teil der Beschreibung: MOSFET P-CH 12V 0.85A SC-70-3</p>
	<p>Datenblätter:  SI1307EDL-T1-GE3.pdf</p>
	<p>RoHs Status: Bleifrei / RoHS-konform</p>
	<p>Lagerzustand: New original, 47156 pcs Stock Available.</p>
	<p>Liefern von: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>

Spezifikationen

Teilenummer	SI1307EDL-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 12V 0.85A SC-70-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	47156 pcs Stock
detaillierte Beschreibung	P-Channel 12V 850mA (Ta) 290mW (Ta) Surface
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-70, SOT-323
Supplier Device-Gehäuse	SC-70-3
Verlustleistung (max)	290mW (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	850mA (Ta)
Rds On (Max) @ Id, Vgs	290 mOhm @ 1A, 4.5V
VGS (th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	5nC @ 4.5V
Antriebsspannung (Max Rds On, Min Rds On)	1.8V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI1307EDL-T1-GE3TR

SI1307EDL-T1-GE3 ist neu im Original, Suche SI1307EDL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1307EDL-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI1307EDL-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1307DL-T1-GE3 Vishay / Siliconix MOSFET P-CH 12V 0.85A SOT323-3</p>	 <p>SI1307EDL VISHAY SI1307EDL VISHAY</p>	 <p>SI1308EDL-T1-E3 Son SI1308EDL-T1-E3 Son</p>	 <p>SI1307DL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 0.85A SOT323-3</p>
 <p>SI1307EDL-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 12V 0.85A SOT323-3</p>	 <p>SI1307EDL-T1-GE3 Vishay / Siliconix MOSFET P-CH 12V 0.85A SC-70-3</p>	 <p>SI1308EDL VB SI1308EDL VB</p>	 <p>SI1308EDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 1.4A SOT323</p>

heiße Teile

Mehr

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|--------------------|--------------------|--------------------|--------------------|--------------------|
| ⊕ SI1305DL | ↔ SI1305DL-T1 | ⇒ SI1305DL-T1-E3 | D SI1305DL-T1-E3 | ⇒ SI1305DL-T1-GE3 |
| ⊕ SI1305DL-T1-GE3 | ⊕ SI1305DL-T1-E3 | D SI1305EDL | ⇒ SI1305EDL-T1-E3 | ⇒ SI1305EDL-T1-E3 |
| ⊕ SI1305EDL-T1-GE3 | ⊕ SI1305EDL-T1-GE3 | ⊕ SI1305LT-T1-E3 | ↔ SI1306DL | ⇒ SI1307-DL-T1-E3 |
| D SI1307DL | ⊕ SI1307DL-T1 | ⊕ SI1307DL-T1-E3 | ⊕ SI1307DL-T1-E3 | ⇒ SI1307DL-T1-GE3 |
| ⇒ SI1307DL-T1-GE3 | ↔ SI1307EDL | ⊕ SI1307EDL-T1-E3 | ⊕ SI1307EDL-T1-E3 | ⇒ SI1307EDL-T1-GE3 |
| ↔ SI1308EDL | ⇒ SI1308EDL-T1-GE3 | D SI1308EDL-T1-GE3 | ⊕ SI13132CNU | ⊕ SI1315DL-T1-GE3 |
| ⊕ SI1315DL-T1-GE3 | D SI1317DL-T1-GE3 | ⇒ SI1317DL-T1-GE3 | ↔ SI1330EDL-T1-E3 | ⇒ SI1330EDL-T1-E3 |
| ⊕ SI1330EDL-T1-GE3 | ⊕ SI1330EDL-T1-GE3 | ↔ SI1400DL-T1 | ⇒ SI1400DL-T1-E3 | ⇒ SI1400DL-T1-E3 |
| ⊕ SI1400DL-T1-GE3 | ⊕ SI1400DL-T1-GE3 | ⊕ SI1401EDH-T1-GE3 | D SI1401EDH-T1-GE3 | ⇒ SI1402DH-T1-GE3 |
| ↔ SI1402DH-T1-GE3 | ⊕ SI1403BDL-T1-E3 | ⊕ SI1403BDL-T1-E3 | ⊕ SI1403BDL-T1-GE3 | ⇒ SI1403BDL-T1-GE3 |

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